

A NOVEL SINGLE SWITCH-CAPACITOR DAC SAR ADC DESIGN

A THESIS

submitted by

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To my Family
and
To the Calmness of Himachal

DECLARATION

I hereby declare that the entire work reported in this thesis is the result of investigations carried out by me in School of Computing and Electrical Engineering, Indian Institute of Technology Mandi, under the joint supervision of **Dr. Sanjeev Manhas** and **Dr. Satinder Sharma**, and that it has not been submitted elsewhere for the award of any degree or diploma. In keeping with general practice, due acknowledgments have been made wherever the work described is based on finding of other investigators.

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THESIS CERTIFICATE

This is to certify that the thesis titled **A NOVEL SINGLE SWITCH-CAPACITOR DAC SAR ADC DESIGN**, submitted by **Ashish S. Joshi**, to the Indian Institute of Technology Mandi, for the award of the degree of **Master of Science (by Research)**, is a bonafide record of the research work done by him under my supervision. The contents of this thesis, in full or in parts, have not been submitted to any other institute or university for the award of any degree or diploma.

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ABSTRACT

Keywords: *SAR ADC, switch-capacitor DAC, RCCM, dynamic comparator*

A switch-capacitor DAC based successive approximation analog to digital converter (SAR-ADC) for sensor-RFID application is presented in this work. To achieve minimum chip area, maximum simplicity is imposed on capacitive DAC; replacing capacitor bank with only one switch-capacitor circuit. The regulated clocked current mirror (RCCM) design is introduced to source (and sink) the stabilized current to (and from) the only capacitor in the circuit. DC reference current from RCCM, charging or discharging the single capacitor in the circuit, is controlled by pulse width modulated signal to realize switch-capacitor DAC. The switch control scheme (SAR control circuit) is built using basic AND gates to generate the control signals for RCCM.

An 8-bit SAR ADC that exhibits a maximum sampling frequency of 100 kHz is designed in 90 nm CMOS technology using Cadence Electronic Design Automation (EDA) tools. Parasitic components extracted from layout are considered in simulation while evaluating the performance of ADC. The use of only one capacitor and reduced transistor count in digital part reduces the silicon area occupied by the ADC to only 0.0098 mm². At 100 kS/s and 1 V supply, the converter consumes only 6.75 μ W of power and achieves SNDR of 48.68 dB (ENOB of 7.79 bits). The quantization energy (E_Q) for this ADC is calculated to be 305 fJ/conv-step while the evaluated figure of merit (FoM) which takes area occupied by the ADC into consideration is 3.87×10^{20} . The high FoM obtained here shows that the proposed ADC acquires minimal silicon area and has sufficiently low power consumption compared to its counterparts in RFID applications.

Further, the thesis presents a proof of concept for feasibility of FinFET transistors in analog to digital converter design. Inherent suppression of short channel effects, reduced sub-threshold and gate-dielectric leakage, good scalability and ease of integration in analog, digital and RF circuits makes SOI FinFET an important device for mixed signal and system on chip (SoC) solutions. We present an 8 bit, switch-capacitor DAC SAR ADC design in 45 nm SOI double gate FinFET technology and benchmarks the simulation results with similar design in 90 nm bulk CMOS.

Maximum drive is obtained while employing shorted gate (SG) FinFET design for regulated clocked current mirror, sampling unit and SAR control circuitry. The option to separately bias the two gates of FinFET and operate them independently is utilized in comparator design to reduce the power dissipation at higher conversion speed. When compared to 90 nm CMOS ADC, this FinFET based ADC consumes only 2.25 μ W of additional power and achieves nine times higher sampling rate.

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